TX-1919RGBW40D180-001H90

PRODUCT SPECIFICATION

Features:

◆Excellent transiting heat from LED chip operating under RGB:350 mA W:700 mA.

◆Mixing any two colors of light, there will be no partial color and color spots uneven phenomenon.

◆High luminous output.

◆No UV.

◆Encapsulated materials are environmentally certified and meet environmental requirements.

Chip Material:

◆Red: AlGaInP

◆Green: GaInN

◆Blue: GaN

◆White: GaN

Emitting Color:

◆Red

◆Green

◆Blue

◆white

Applications:

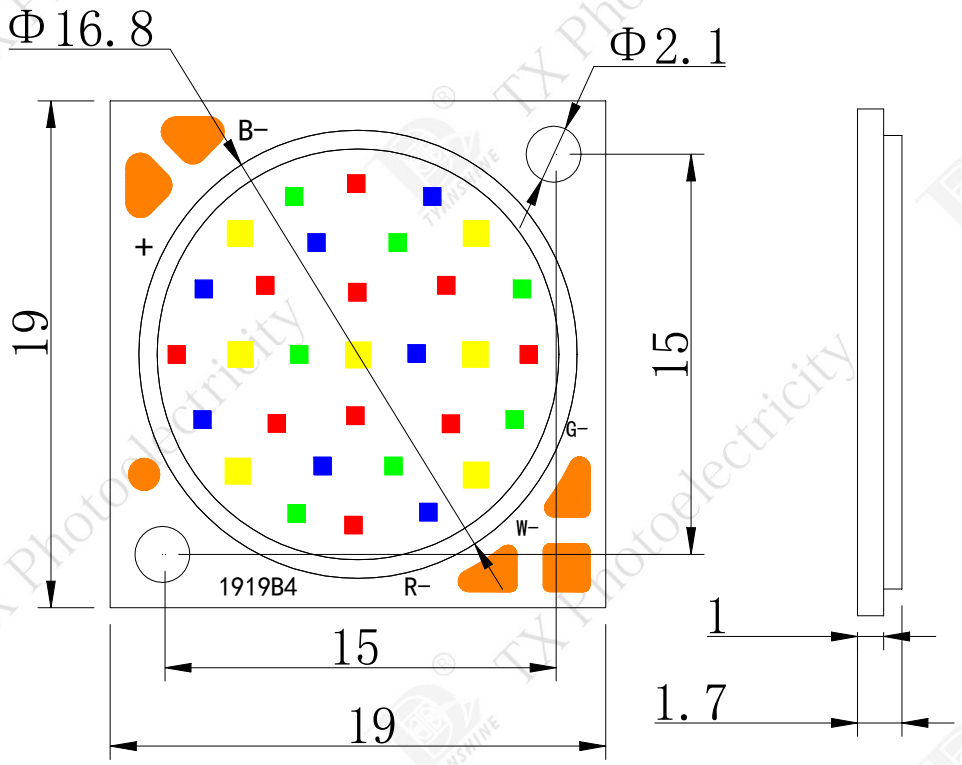
◆Entertainment lighting

◆Landscape lighting

◆Commercial lighting

◆Decorative lighting

Package Dimensions:



Notes:

1.All dimensions are in millimeters .

2.Tolerances unless otherwise mentioned are ±0.1mm .

Absolute Maximum Ratings (Tc=25℃)

Parameter	Symbol		Ratings	Unit
Forward Current	IF	R	350	mA
		G	350	
		B	350	
		W	700	
Reverse Voltage	V_R		Not designed for reverse operation	V
Power Dissipation	P_D	R	8000	mW
		G	8000	
		B	8000	
		W	16000	
Junction Temperature	Tj	R	115	℃
		G	150	
		B	150	
		W	150	
Electrostatic Discharge Threshold (ESD)	ESD		2000	V
Storage Temperature	T_{stg}		-20~+70	℃
Operation Temperature	T_{opr}		-40~+100	

Notes:

1.Specifications are subject to change without notice.

2.Under the stipulated Characteristics parameters above, the life span of the LED is more than 50,000hours.

3.The data on this specification is for reference only and the actual data is in accordance with the acknowledgment.

4.Precautions for ESD:

STATIC SHIELD Electricity and surge damages the LED. It is recommended to use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.

Electrical Optical Characteristics (Tc=25°C)

Parameter	Symbol	Condition	Emitting Color	Min.	Typ.	Max.	Units
Luminous Flux	φ_v	$I_{f(RGB)}$=350mA $I_{f(W)}$=700mA	R	320	450	—	lm
			G	480	650	—	
			B	88	115	—	
			W	640	850	—	
Dominant Wavelength	λd		R	618	623	628	nm
			G	522	525	528	
			B	452	455	457	
Correlated Colour Temperature	CCT		W	4100	4200	4300	K
Color Rendering Index	Ra		W	90	92.5	—	—
Peak-emission Wavelength	λp		R	627	632	637	nm
			G	515	520	525	
			B	447	452	457	
Spectral Line Half-Width	△λ		R	15	20	25	nm
			G	25	30	35	
			B	15	20	25	
			W	22	27	32	
Forward Voltage	V_f		R	20	21.5	23	V
			G	20	21.5	23	
			B	20	21.5	23	
			W	20	21.5	23	
Viewing Angle at 50％IV	$2\theta_{1/2}$	—	—	—	120	—	Deg
Thermal Resistance Junction to Case	$R\theta_{J-C}$	$I_{f(RGB)}$=350mA $I_{f(W)}$=700mA	—	—	1.5	—	K/W
Temperature Coefficient of Voltage	V△F/T		—	—	-2	—	mV/℃

Notes:

1.Luminous intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.

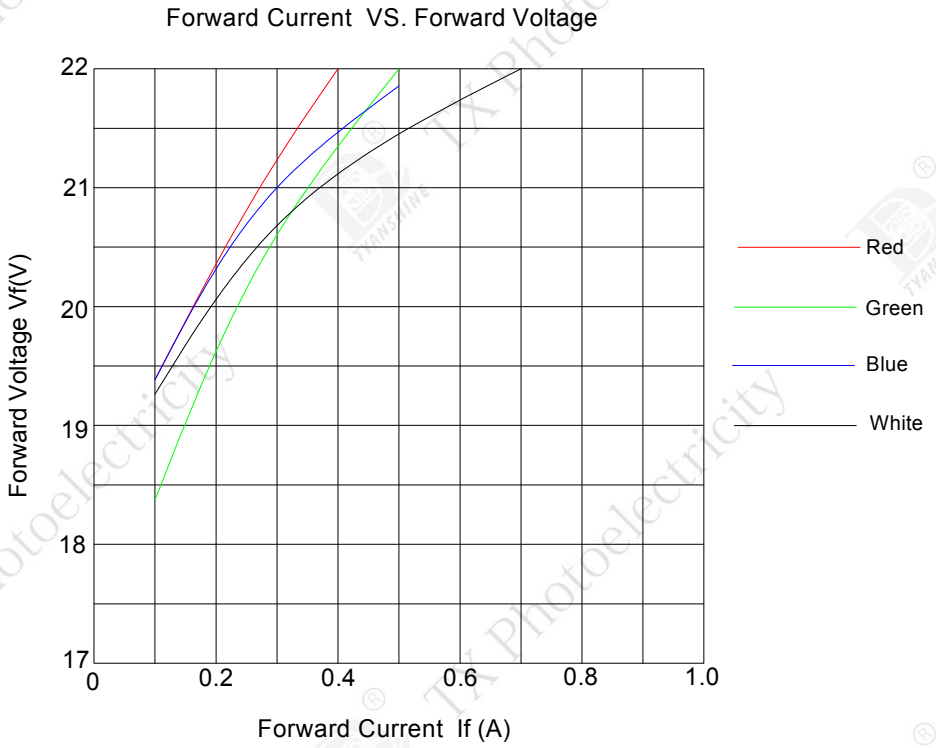
2.$\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.

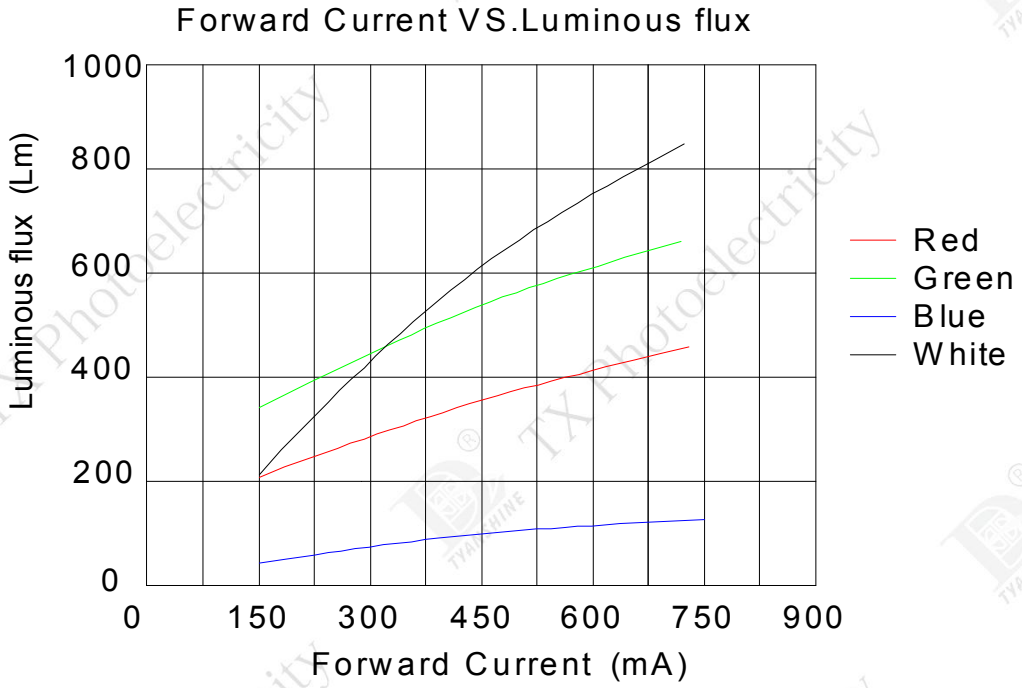
3.Luminous flux measurement tolerance:±15%.

4.Forward voltage measurement tolerance:±0.15V.

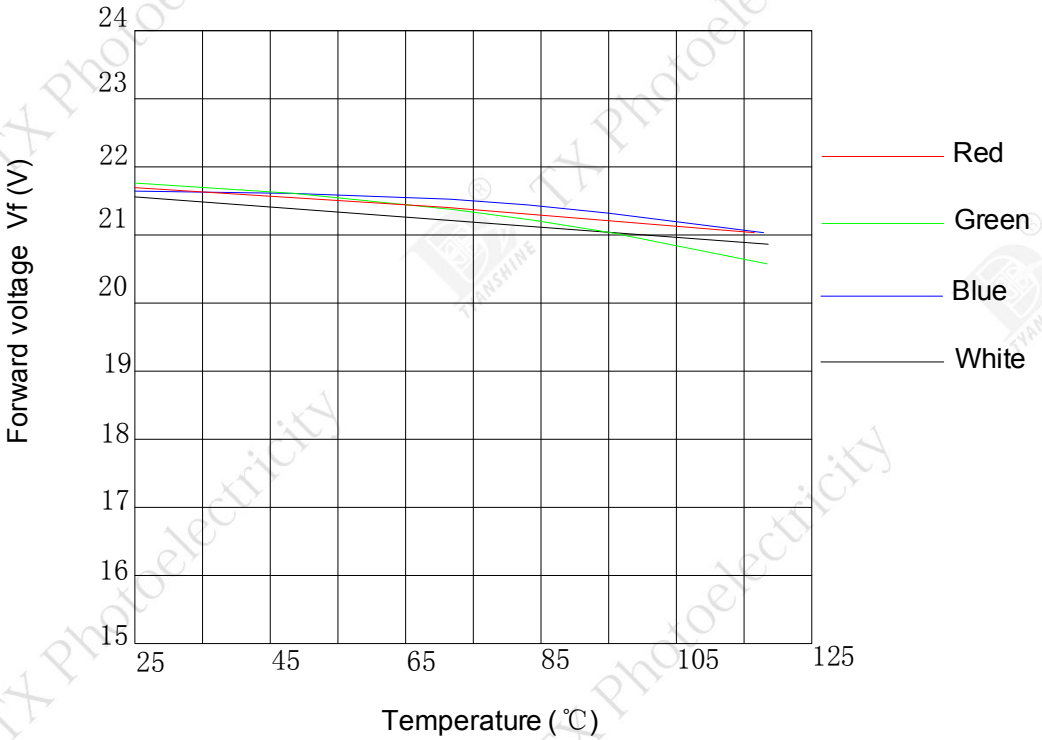
Typical Electrical/Optical Characteristics Curves

(25℃ Ambient Temperature Unless Otherwise Noted)

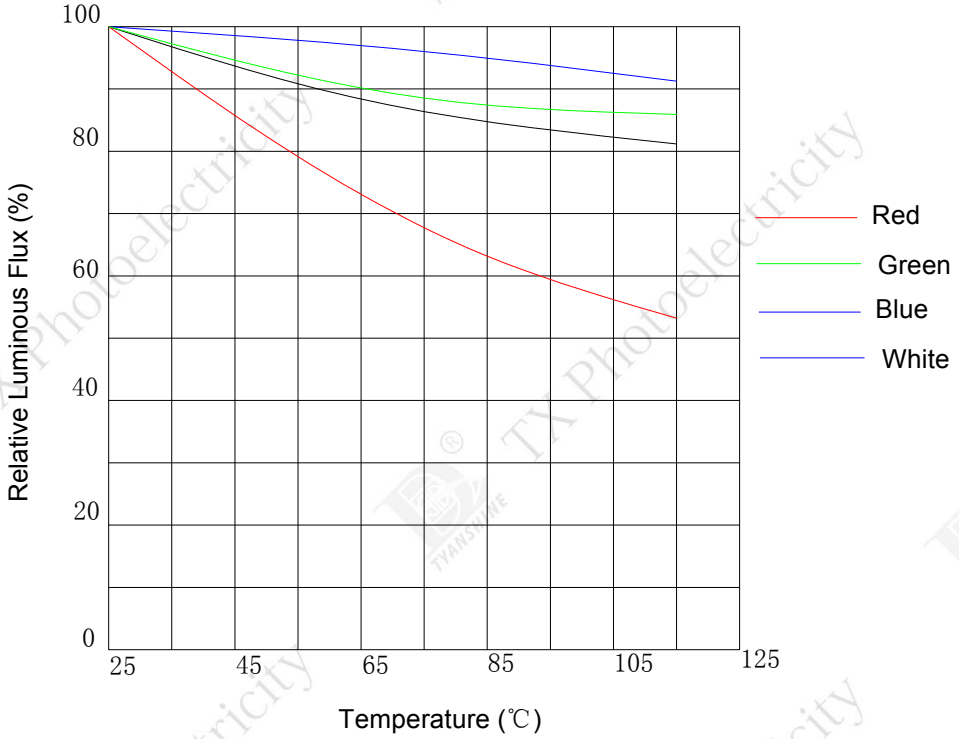




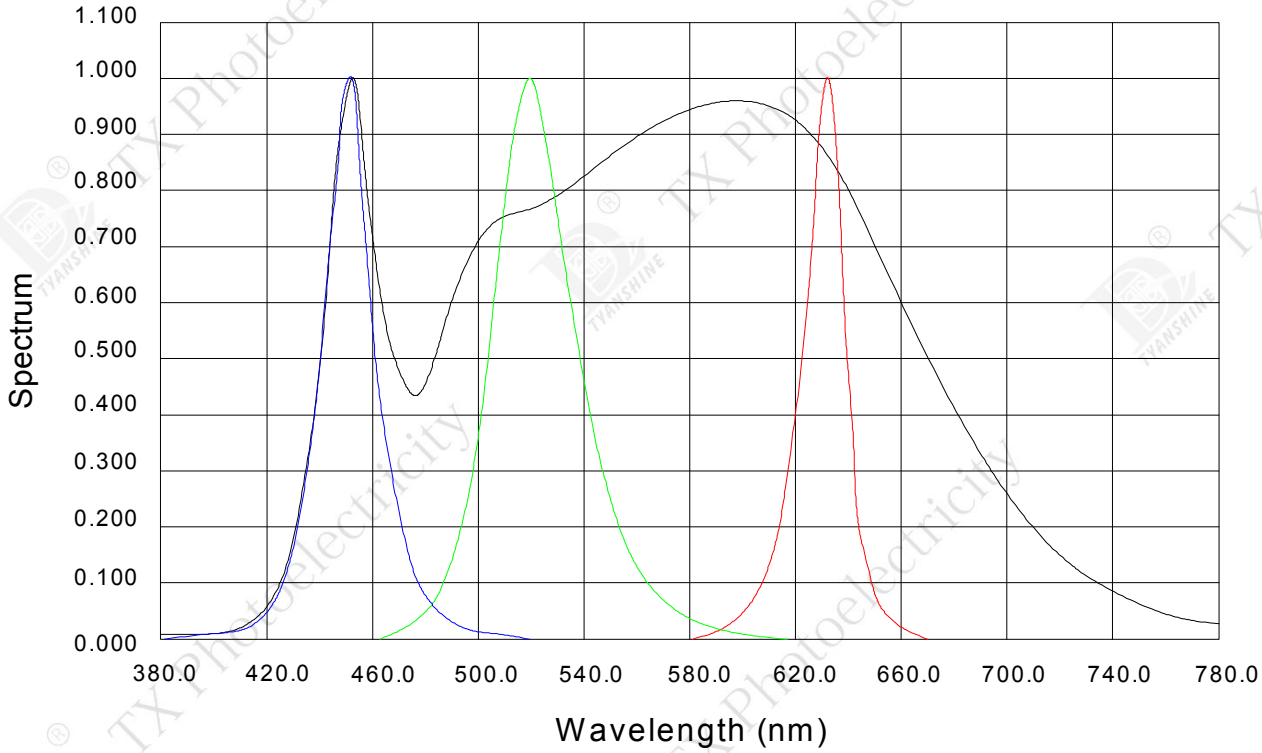
Temperature VS. Forward Voltage (IF (RGB)=350mA IF(W)=700mA)



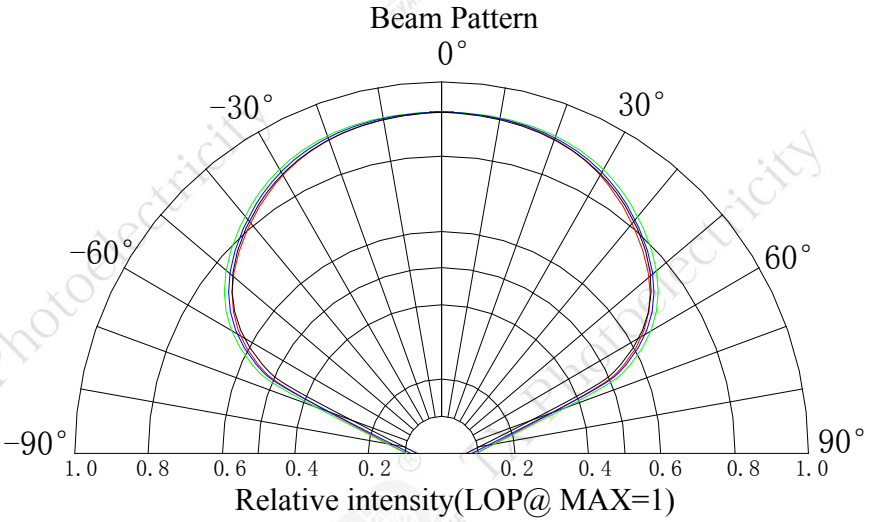
Temperature VS. Relative Luminous Flux (IF(RGB)=350mA IF(W)=700mA)



Relative Spectral Distribution



Beam Pattern



Notes:

1. 2θ 1/2 is the off axis angle from lamp centerline where the luminous intensity is 1/2 of the peak value.
2. View angle tolerance is ± 5°.